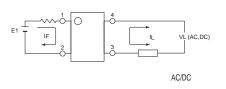
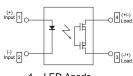
APSEMI®

Parameter	Symbol	Rating	Units	
Load Voltage	VL	400	V	
Load Current	lL .	0.12	Α	
On-Resistance	Ron	20	Ω	
I/O Breakdown Voltage	V/io	5000	Vrms	





- 1. LED Anode
- 2. LED Cathode
- 3.4. Drain(MOS FET)



APSEMI PhotoRelays

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

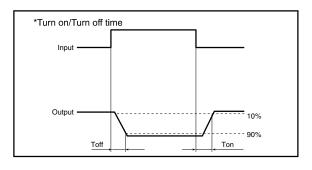
Applications

- Telecom/Datacom switching
- Multiplexers
- . Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems

- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- **Energy Management**
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

	Output rating					
Category	Category Load voltage Load current Package	Part No.	Packing quantity			
AC/DC	400)/	0.404	DIP-4	GAQY414E	100pcs/tube	
AC/DC 400V	0.12A	SMD-4	GAQY414EH	1000pcs/1reel		





Absolute Maximum Ratings (Ta = 25°C)

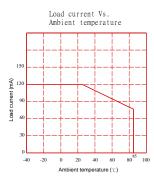
	Item	Symbol	Value	Units	Note
	Continuous LED Current		50	mA	
Input	Peak LED Current	IFР	500	mA	f=100Hz, duty=1%
	LED Reverse Voltage	VR	5	V	
	Input Power Dissipation	P _{In}	75	mW	
	Load Voltage	VL	400	V(AC peak or DC)	
Output	Load Current	lι	0.12	Α	
	Peak Load Current	Peak	0.3	А	100ms(1 pulse)
	Output Power Dissipation	Pout	500	mW	
Total Powe	er Dissipation	Рт	550	mW	
I/O Breakd	own Voltage	V _{I/O}	5000	Vrms	RH=60%, 1min
Operating	Temperature	Topr	-40 to +85	°C	
Storage Te	Storage Temperature		-40 to +100	°C	
Pin Solderi	ng Temperature	T _{sol}	260	°C	10 sec max.

Electrical Specifications (Ambient Temperature: 25°C)

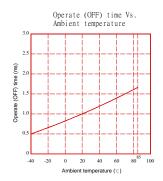
	Item	Symbol	MIN.	TYP.	MAX.	Units	Conditions
	LED Forward Voltage	VF		1.2	1.4	V	I⊧=10mA
Input	Operation LED Current	IF on		0.5	3.0	mA	
	Recovery LED Current	I F off		0.35	0.5	mA	
	Recovery LED Voltage	V _F off	0.5			V	
Output	On-Resistance	Ron		20	50	Ω	I _F =5mA,I∟=Max Time to flow is within 1 sec.
·	Off-State Leakage Current	ILeak			1.0	uA	V _L =Rating
	Output Capacitance	Cout		165		pF	V∟=0, f=1MHz
Transmis	Turn-On Time	Ton		0.02	1.0	ms	I⊧=5mA, I∟=Max
sion	Turn-Off Time	Toff		0.5	3.0	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	1010			Ω	DC500V
Coupled	I/O Capacitance	C _{I/O}		0.8		pF	f=1MHz

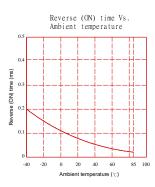
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

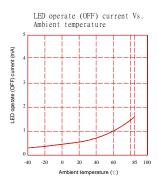
Engineering Data

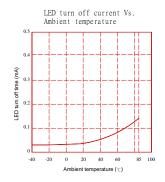


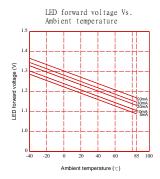


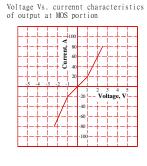


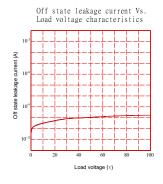


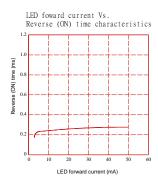


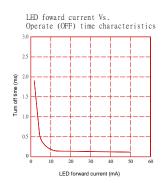


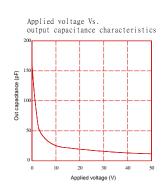




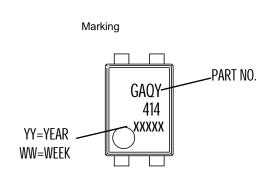


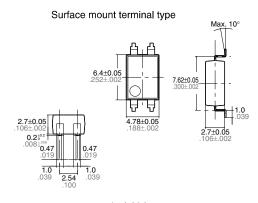






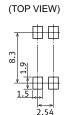
Dimensions and SMD-4 Package Unit: mm





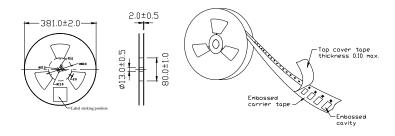
Terminal thickness: t = 0.2 General tolerance: ±0.1

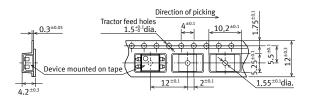
Recommended mounting pad



Tolerance: ±0.1

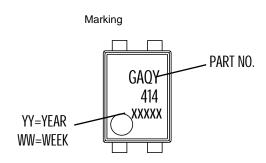
Tape dimensions (tape reel)



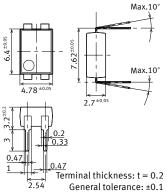


Dimensions and DIP-4 Package

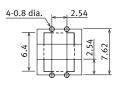
Unit: mm



Surface mount terminal type



PC board pattern (BOTTOM VIEW)



Tolerance: ±0.1

Tape dimensions (tape reel)

DIP type

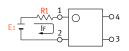
Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.

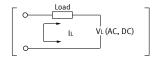




Using Methods

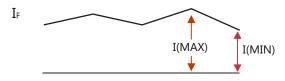
Examples of resistance value to control LED forward current (IF=5mA)





E1	R1 (Approx)
3.3V	300 Ω
5.0V	600 Ω
12V	1.9KΩ
24V	4.1K Ω

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



Recommended Operating Conditions

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

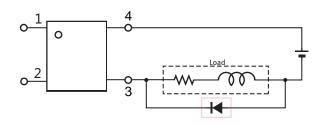
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	lF	5.0	7.0	30	mA

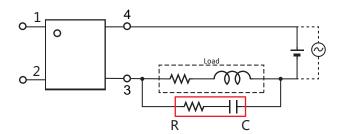
Protection Circuit

Output spike voltages:if an inductive load generates spike voltages which exceed heabsolute maximum rating, the spike voltage shall be limited.

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.





When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.

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